VOLTAGE REGULATION S-8821 Series S-8821 Series

1.6 to 5.0 V

The S-8821 series is a CMOS step-up charge pump DC-DC converter with a voltage regulation function. The S-8821 series consists of an oscillation circuit, a controller, a reference voltage circuit, an error amplifier circuit, and an output switching transistor, and can regulate the output voltage by PFM control. Since small ceramic capacitors can be used for the pump capacitor, input capacitor, and output capacitor, the mounting area can be minimized.

Features

- Step-up PFM control CMOS charge pump
- Power supply voltage:
- Output voltage:
- Output voltage accuracy:
- Built-in soft start circuit:
- Output current
- Oscillation frequency:
- ON/OFF function:
- Ultra-small package:
- Lead-free products

Applications

- Lithium ion battery driven applications
- Local power supply
- Power supply for white LED display backlights

Packages

Package Name	Drawing Code				
T ackage Maine	Package	Таре	Reel		
SOT-23-6W	MP006-B	MP006-B	MP006-B		
6-Pin SNB(B)	BD006-A	BD006-A	BD006-A		
6-Pin SON(A)	PB006-A	PB006-A	PB006-A		

2.5 to 5.5 V, selectable in 0.1 V steps. ±2 % max. 1.0 ms typ.

- 25 mA (V_{IN} =($V_{OUT(S)} \times 0.80$) V) 1.0 MHz typ. During standby: 1 μ A max.
- SOT-23-6W, 6-Pin SNB(B), 6-Pin SON(A)

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Block Diagram



Figure 1

Selection Guide

• The output voltage and packages for the S-8821 Series can be selected at the user's request. Refer to the "Product name selection guide" for the meanings of the characters in the product name and "Product name list" for the full product names.

1. Product name selection guide

1.1 SOT-23-6W, 6-Pin SON(A) Packages



***1.** Refer to the taping specifications at the end of this book.

*2. Refer to the product name list.



*1. Refer to the taping specifications at the end of this book.

*2. Refer to the product name list.

2. Product name list

		Table 1	
Output Voltage	SOT-23-6W	6-Pin SON(A)	6-Pin SNB(B)
3.0 V	S-882130AMH-M2FTFG	S-882130APB-M2FTFG	S-882130ABD-M2F-TF
3.3 V	S-882133AMH-M2ITFG	S-882133APB-M2ITFG	S-882133ABD-M2I-TF
3.6 V	S-882136AMH-M2LTFG	—	—
4.5 V	S-882145AMH-M2UTFG	—	—
5.0 V	S-882150AMH-M2ZTFG	S-882150APB-M2ZTFG	S-882150ABD-M2Z-TF
5.5 V	S-882155AMH-M3ETFG	—	—

Remark Contact the SII sales department for products with an output voltage other than those specified above.

Pin Configurations



Table 2



Pin No.	Symbol	Pin Description
1	VIN	Voltage input pin
2	C+	Charge-pump pump capacitor connection pin (positive pin)
3	C–	Charge-pump pump capacitor connection pin (negative pin)
4	ON/OFF	Shutdown pin High level (H): normal operation (step-up) Low level (L) : step-up halt (all circuit halt)
5	GND	GND pin
6	VOUT	Voltage output pin

Figure 2



*1. Connect the heatsink of back side at shadowed area to the board, and set electric potential open or GND. However, do not use it as the function of electrode.

Figure 3

Table 3

Pin No.	Symbol	Pin Description
1	VOUT	Voltage output pin
2	ON/OFF	Shutdown pin High level (H): normal operation (step-up) Low level (L): step-up halt (all circuit halt)
3	GND	GND pin
4	C–	Charge-pump pump capacitor connection pin (negative pin)
5	C+	Charge-pump pump capacitor connection pin (positive pin)
6	VIN	Voltage input pin

6-Pin SON(A)

Top view 6 5 4 0

Pin No.	Symbol	Pin Description
1	ON/OFF	Shutdown pin High level (H): normal operation (step-up) Low level (L): step-up halt (all circuit halt)
2	GND	GND pin
3	C–	Charge-pump pump capacitor connection pin (negative pin)
4	C+	Charge-pump pump capacitor connection pin (positive pin)
5	VIN	Voltage input pin
6	VOUT	Voltage output pin

Figure 4

2 3

1

Absolute Maximum Ratings

Table 5

		(Ta=25°C unless otherwise specified)		
Items	Symbols	Absolute Maximum Ratings		Units
C+ pin voltage	V _{C+}	V _{GND} -0.3 t	o V _{GND} +7.5	V
C– pin voltage	V _{C-}	V _{GND} -0.3	to V _{GND} +7	
VIN pin voltage	V _{IN}	V _{GND} -0.3 te	o V _{GND} +5.5	
VOUT pin voltage	V _{OUT}	V _{GND} –0.3 to V _{GND} +7		
ON/OFF pin voltage	$V_{ON/\overline{OFF}}$	V _{GND} -0.3 to V _{IN} +0.3		
Operating temperature range	T _{OPR}	-40 to +85		°C
Storage temperature range	T _{STG}	-40 to +125		
Power dissipation	P _{D1}	SOT-23-6W	300	mW
	P _{D2}	6-Pin SON(A)	200	
	P _{D3}	6-Pin SNB(B)	90	

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Figure 5 Power Dissipation of The Packages

Electrical Characteristics

		$(V_{IN}=(V_{OUT(S)}\times 0.)$	60) V ^{*1} T	a=25°C i	inless off	nerwise s	necified)
Items	Symbols	Conditions	Min.	тур.	Max.	Units	Test circuits
Operation input voltage	V _{IN}	V _{OUT(S)} ≤ 2.9 V	1.6		5.0	V	2
		V _{OUT(S)} > 2.9 V	$V_{OUT(S)} imes 0.54$		5.0		
Output voltage* ²	$V_{\text{OUT}(\text{E})}$	I _{out} =10 mA	$\begin{array}{c} V_{OUT(S)} \times \\ 0.98 \end{array}$	V _{OUT(S)}	$V_{OUT(S)} \times 1.02$		
Output current*3	I _{OUT}	$V_{IN} = (V_{OUT(S)} \times 0.54) V^{*6}$	5			mA	
		$V_{IN} = (V_{OUT(S)} \times 0.60) V^{*1}$	15		—		
		$V_{IN}=(V_{OUT(S)} \times 0.80) V$	25		—		
Line regulation	ΔV_{OUT1}		_	50	100	mV	
Load regulation	ΔV_{OUT2}	I _{OUT} =0.1 mA to 10 mA	_	40	80		
Ripple voltage ^{*4}	V _{RIP}	I _{OUT} =10 mA		70		mV_{p-p}	
Maximum oscillation frequency	f_{osc}	V_{OUT} =($V_{OUT(S)} \times 0.60$) V, Measure waveform at C- pin	800	1000	1200	kHz	
Efficiency⁵⁵	η	V _{IN} =(V _{OUT(S)} × 0.54) V, V _{OUT(S)} ≥ 3.0 V, I _{OUT} =5 mA	_	90	—	%	1
Operation consumption current	I _{SS1}	$V_{IN}=V_{OUT(S)},$ $V_{OUT}=(V_{OUT(S)}+0.5) V$	_	35	60	μA	2
Standby consumption current	I _{SSS}		—	0.3	1.0		1
ON/OFF pin input voltage (high level)	V_{SH}	$V_{\text{IN}}\text{=}(V_{\text{OUT}(S)} \times 0.54) \text{ V}^{\text{*6}} \text{ to } 5.0 \text{ V}$	1.5	_	—	V	
ON/OFF pin input voltage (low level)	V_{SL}	$V_{\text{IN}}\text{=}(V_{\text{OUT}(S)} \times 0.54) \text{ V}^{\text{*6}} \text{ to } 5.0 \text{ V}$	—	_	0.3		
ON/OFF pin input current (high level)	I _{SH}	$V_{\text{IN}}\text{=}(V_{\text{OUT}(S)} \times 0.54) \text{ V}^{\text{*6}} \text{ to } 5.0 \text{ V}$	-0.1		0.1	μA	
ON/OFF pin input current (low level)	I _{SL}	$V_{\text{IN}}\text{=}(V_{\text{OUT}(S)} \times 0.54) \text{ V}^{\text{*6}} \text{ to } 5.0 \text{ V}$	-0.1		0.1		
Soft start time	t _{ss}	I _{OUT} =10 mA	0.2	1.0	4.0	ms	

Table 6

*1. In case of $V_{OUT} \le 3.3 \text{ V}, V_{IN}=2.0 \text{ V}$

*2. V_{OUT(E)}: Actual output voltage V_{OUT(S)}: Specified output voltage

***3.** The output current at which the output voltage becomes 97 % of V_{OUT(E)} after gradually increasing the output current.

- *4. Design assurance
- *5. The ideal efficiency is indicated by the following expression. Efficiency (η)=(V_{OUT} × I_{OUT}) / (2.0 × V_{IN} × I_{OUT})

***6.** In case of $V_{OUT} \le 2.9 \text{ V}, V_{IN} = 1.6 \text{ V}$

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Test Circuits







Figure 7

Operation

1. Basic operation

Figure 8 shows the block diagram of the S-8821 Series.

The S-8821 series controls the output voltage by using the pulse frequency modulation (PFM) method. The SW1 to SW4 switching transistors are switched ON/OFF with the clock generated by the internal oscillator circuit, and operates the step-up charge pump.

The output voltage is fed back and the voltage split by feedback resistances R_s and R_f and reference voltage (V_{ref}) are compared by a comparator. This comparator signal is used to modulate the oscillation pulse frequency in order to keep the output voltage constant.



Figure 8

2. Step-up Charge Pump

The step-up charge pump steps up the voltage by switching ON/OFF of the SW1 to SW4 switching transistors.

First, in order to charge the pump capacitance (C_{PUMP}), set SW1 to OFF, SW2 to ON, SW3 to OFF, and SW4 to ON (charge cycle). Following charging the electricity, in order to discharge the charged electricity to the output capacitance (C_{OUT}), SW1 set the switches as to ON, SW2 to OFF, SW3 to ON, and SW4 to OFF (discharge cycle).

The input voltage can be stepped up to a constant voltage value by repeating this charge cycle and discharge cycle.

Figure 9 shows the charge cycle, and Figure 10 shows the discharge cycle.



Figure 9



Figure 10

3. Shutdown Pin (ON/OFF Pin)

Setting the ON/OFF pin to the Low level ("L") causes the voltage of the VOUT pin to change to the GND level and simultaneously the operation of all the internal circuit to stop. At this time, the consumption current is largely reduced, to a level of approximately $0.3 \mu A$.

The structure of the ON/OFF pin is as shown in **Figure 11**. Since the ON/OFF pin is neither pulled down nor pulled up internally, do not use it in the floating state. When the ON/OFF pin is not used, connect it to the VIN pin.

Table 7

ON/OFF pin	Internal circuit	VOUT pin voltage
"H": Power on	Operating	Set value
"L": Power off	Stop	V _{GND} level



Figure 11

4. Soft Start Function

The S-8821 Series features a built-in soft start circuit. Upon power application or when the ON/\overline{OFF} pin is switched from "L" to "H", the output voltage gradually rises over the soft start time, and the output current is gradually output as a result. This soft start function reduces the input current rush.

External Capacitor Selection

1. Input and Output Capacitors (C_{IN}, C_{OUT})

The input capacitor (C_{IN}) lowers the power supply impedance and averages the input current. The C_{IN} value is selected according to the impedance of the power supply that is used. Select a ceramic capacitor with a small equivalent series resistance (ESR). Although this figure varies according to the impedance of the power supply that is used as well as the load current value, it is generally in the range of 4.7 μ F to 10 μ F.

For the output capacitor (C_{OUT}), select a ceramic capacitor with a small ESR for smoothing the ripple voltage. A value of 10 μ F is recommended for the capacitance value. Use of a capacitor with a capacitance lower than 10 μ F results in a larger ripple voltage. Conversely, use of a capacitor with a capacitance greater than 10 μ F results in the output voltage not being able to rise up to setting value and the impossibility to obtain the desired output current.

2. Pump Capacitor (C_{PUMP})

The pump capacitor (C_{PUMP}) is required for stepping up the voltage. Select a ceramic capacitor with a small ESR. A capacitance value of 0.10 μ F is recommended. Use of a capacitor with a capacitance greater than 0.10 μ F results in a larger ripple voltage. Conversely, use of a capacitor with a capacitance lower than 0.10 μ F results in the output voltage not being able to raise up to setting value and the impossibility to obtain the desired output current.

Precautions

- Regarding the wiring to the VIN pin, VOUT pin, C+ pin, C- pin and GND pin, be careful to perform pattern wiring so as to obtain low impedance.
- Always connect a capacitor to the VOUT pin, C+ pin, and C- pin.
- Connect C_{IN} and C_{OUT} in the vicinity of the IC and sufficiently strengthen the wiring for GND pin and VIN pin in order to lower the impedance of the wiring resistance, etc. High impedance may cause unstable operation.

Moreover, in selecting $C_{\mbox{\scriptsize IN}}$ and $C_{\mbox{\scriptsize OUT}},$ perform a full evaluation of the actual usage conditions.

Connect C_{PUMP} in the vicinity of the IC and sufficiently strengthen the wiring for the C+ pin and C- pin in order to lower the impedance of the wiring resistance, etc. High impedance may cause instable operation.

Moreover, in selecting $C_{\text{PUMP}},$ perform a full evaluation of the actual usage conditions.

- The ON/OFF pin is configured as shown in **Figure 11** and is neither pulled up or down internally, so do not use this pin in a floating state. When not using the ON/OFF pin, connect it to the VIN pin. Moreover, please do not apply voltage higher than VIN + 0.3 V to an ON/OFF pin. Current flows for a VIN pin through the protection diode inside IC.
- Since this IC consists of double step-up circuits, it cannot set more than twice voltage of VIN to VOUT(S).
- Be careful about the usage conditions for the input/output voltages and output current to make sure that dissipation within the IC does not exceed the allowable power dissipation of the package. For reference, the calculation of the power consumption in this IC is shown below. $P_D=(V_{IN} \times 2.0 - V_{OUT}) \times (I_{OUT})$

Reference: V_{IN} =4.2 V, V_{OUT} =5.5 V, I_{OUT} =10 mA P_{D} =(4.2 × 2.0 - 5.5) × 0.010=29 mW

- Since the information described herein is subject to change without notice, confirm that this is the latest one before using.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
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I_{OUT}=10 mA, Ta=25°C

4.5

V_{IN}=3.0 V, Ta=25°C

5.0 5.5

Typical Characteristics

(1) Output voltage vs. Operation input voltage

S-882133A



(2) Output voltage vs. Output current

S-882133A





S-882133A



S-882150A

S-882150A

5.30

5.20

5.10

4.80

S-882150A

5.30

5.20

5.10

4.80

4.70 └─ 0

5

10

15

I_{OUT} [mA]

20

25

30

∑ 5.00 > 4.90

2.5

3.0

3.5 4.0

V_{IN} [V]

∑ 5.00 > 4.90



(4) Ripple voltage vs. Operation input voltage



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(5) Efficiency^{*1} vs. Operation input voltage

S-882133A





(6) Maximum oscillation frequency vs. Operation input voltage











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(7) Load fluctuation



(8) Input voltage fluctuation

S-882133A



S-882150A











No. MP006-B-P-SD-1.0

TITLE	SOT236-B-PKG Dimensions		
No.	MP006-B-P-SD-1.0		
SCALE			
UNIT	mm		
S	Seiko Instruments Inc.		







Seiko Instruments Inc.











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